FFPF10UP60S

10 A, 600 V Ultrafast Diode

Description

The FFPF10UP60S is an ultrafast diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder and UPS application.

Features

- Ultrafast Recovery, $t_{RR} = 40 \text{ ns}$ (@ $I_F = 1 \text{ A}$)
- Max Forward Voltage, $V_F = 2.2 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- General Purpose
- SMPS, Power Switching Circuits
- Free-Wheeling Diode for Motor Application
- Welder, UPS

ABSOLUTE MAXIMUM RATINGS

 $T_C = 25^{\circ}C$ unless otherwise noted

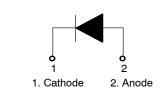
Symbol	Parameter	Rating	Unit
VRRM	Peak Repetitive Reverse Voltage	600	V
VRWM	Working Peak Reverse Voltage	600	V
lf(AV)	Average Rectified Forward Current @ $T_C = 60$ °C	10	Α
IFSM	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave		Α
ТJ, Tsтg	TJ, TSTG Operating Junction and Storage - 65 Temperature + 17		°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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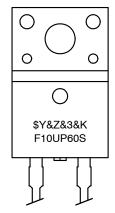
www.onsemi.com





TO-220, 2-Lead CASE 221AS

MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z&3 = Data Code (Year & Week)

&K = Lot

F10UP60S = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFPF10UP60S

THERMAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Unit
Rejc	Maximum Thermal Resistance, Junction to Case	4.5	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity	
FFPF10UP60STU	F10UP60S	TO-220F-2L	Tube	N/A	N/A	30	

ELECTRICAL CHARACTERISTICS T_C = 25°C unless otherwise noted

Parameter	Conditions		Min.	Тур.	Max.	Unit
V _F (Note 1)	Maximum Instantaneous Forward Voltage $I_F = 10 \text{ A}$ $I_F = 10 \text{ A}$	T _C = 25°C T _C = 100°C	- -	- -	2.2 2.0	V
I _R (Note 1)	Maximum Instantaneous Reverse Current @ rated V _R	T _C = 25°C T _C = 100°C	- -	- -	100 500	μΑ
t _{RR}	$I_F = 1 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$	T _C = 25°C	-	-	25	ns
^t RR IRR Q _{RR}	Reverse Recovery Time Reverse Recovery Current Reverse Recovery Charge $(I_F = 8 \text{ A, } di_F/dt = 200 \text{ A/}\mu\text{s, } V_R = 390 \text{ V})$		- - -	34 1.0 17	40 1.5 30	ns A nC
t _{RR}	Maximum Reverse Recovery Time (I _F =10 A, di _F /dt = 200 A/ μ s, V _R = 390 V)		-	58	_	ns
W _{AVL}	Avalanche Energy (L = 40 mH)		20	-	-	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse Width = 300 μs, Duty Cycle = 2%

Test Circuit and Waveforms

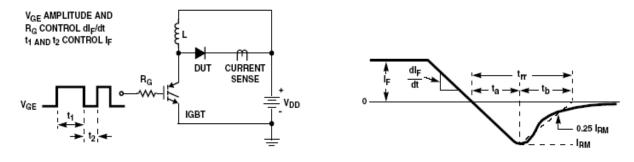


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

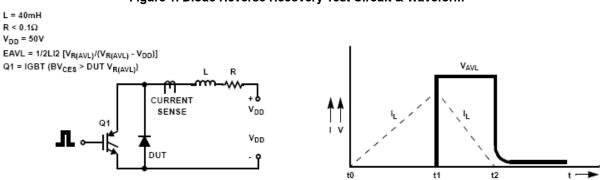
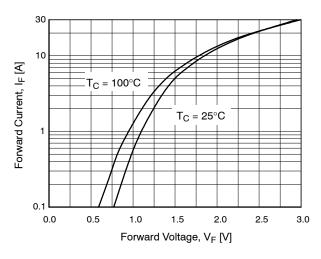


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

FFPF10UP60S

TYPICAL PERFORMANCE CHARACTERISTICS

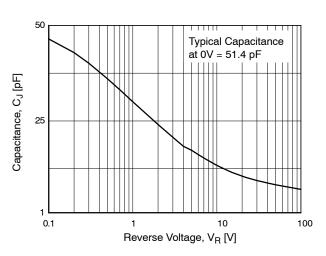
 $T_C = 25^{\circ}C$ unless otherwise noted



1000 100 Reverse Current, IR [µA] T_C = 100°C 10 T_C = 25°C 0.01 1E-3 0 100 200 300 400 500 600 Reverse Voltage, V_R [V]

Figure 3. Typical Forward Voltage Drop

Figure 4. Typical Reverse Current



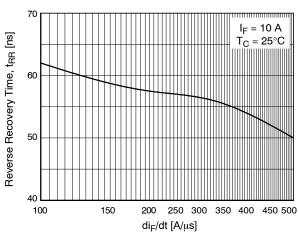
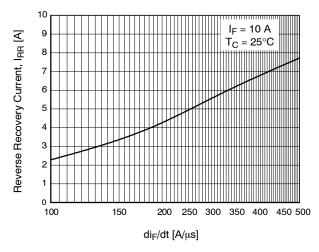


Figure 5. Typical Junction Capacitance

Figure 6. Typical Reverse Recovery Time



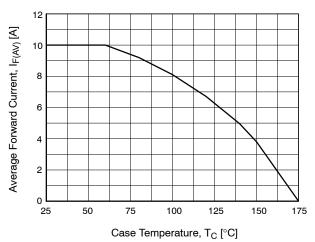
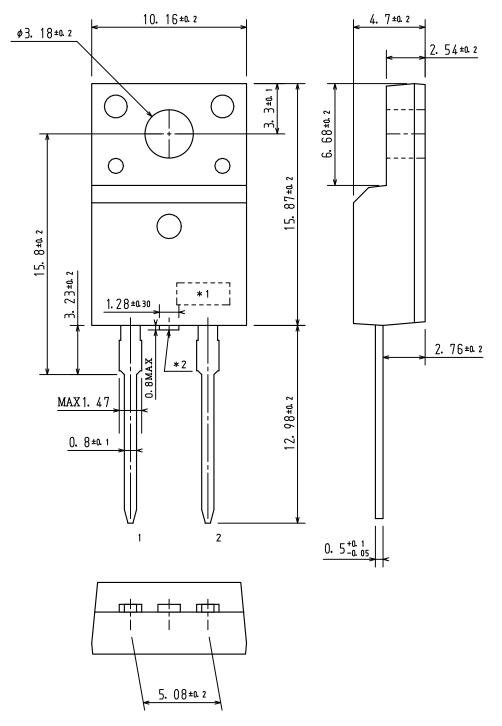


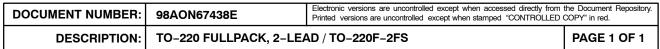
Figure 7. Typical Reverse Recovery Current

Figure 8. Forward Current Derating Curve

TO-220 Fullpack, 2-Lead / TO-220F-2FS CASE 221AS ISSUE O

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